

SEMICONDUCTOR TECHNICAL DATA

Schottky Barrier Rectifier Reverse Voltage 20V~40V, Forward Current 3.0 Ampere

Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Low power loss, high efficiency
- For use in low voltage high frequency inverters, free wheeling, and polarity protection applications
- Guardring for overvoltage protection





Mechanical Data

- Case: JEDEC DO-201AD molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026 High temperature soldering guaranteed: 250°C/10 seconds 0.375" (9.5mm) lead length, 5lbs (2.3kg) tension
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.041 ounce, 1.15 grams



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

$(T_A = 25^{\circ}C \text{ unless otherwise noted})$					
Parameter	Symbols	1N5820	1N5821	1N5822	Units
Maximum repet tive peak reverse voltage	V _{RRM}	20	30	40	Volts
Maximum RMS voltage	V _{RMS}	14	21	28	Volts
Maximum DC blocking voltage	V _{DC}	20	30	40	Volts
Non-repet tive peak reverse voltage	V _{RSM}	24	36	48	Volts
Maximum average forward rect f ed current 0.375" (9.5mm) lead length at T _L =95°C	I _{F(AV)}	3.0			Amps
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) at T _L =75°C	I _{FSM}	80.0			Amps
Maximum instantaneous forward voltage at 3.0 (Note 1)	V _F	0.475	0.500	0.525	Volts
Maximum instantaneous forward voltage at 9.4 (Note 1)	V _F	0.850	0.900	0.950	Volts
Maximum average reverse current at rated DC blocking voltage (Note 1) $@T_A = 25^{\circ}C$	I _R	2.0 20			mA
Typical thermal resistance (Note 2)	R _{eja} R _{ejl}	40 10			°C/W
Operating junction temperature range	T,	-55 to +125			°C
Storage temperature range	T _{stg}	-55 to +150			°C

Notes 1. Pulse test: 300us pulse width, 1% duty cycle

2. Thermal resistance from junction to lead vertical P.C.B. mounted, 0.500" (12.7mm) lead length with 2.5 x 2 5" (63.5 x 63.5mm) copper pad





RATINGS AND CHARACTERISTIC CURVES





10

0.1

Reverse Voltage (V)

10

1.0

First Silicon

0

0.1

1

t, Pulse Duration (sec.)

10

100

100